Preferred Device

# POWERTAP<sup>™</sup> II SWITCHMODE<sup>™</sup> Power Rectifier

These state-of-the-art devices use the Schottky Barrier principle with a platinum barrier metal.

## Features

- Dual Diode Construction May Be Paralleled for Higher Current Output
- Guardring for Stress Protection
- Low Forward Voltage
- 150°C Operating Junction Temperature
- Pb–Free Package is Available\*

### **Mechanical Characteristics:**

- Case: Epoxy, Molded with metal heatsink base
- Weight: 80 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant
- Top Terminal Torque: 25–40 lb–in max
- Base Plate Torques: See procedure given in the Package Outline Section

## MAXIMUM RATINGS

$\begin{tabular}{ c c c c c } \hline Rating & Symbol & Value & Unit \\ \hline Peak Repetitive Reverse Voltage & V_{RRM} & 60 & V \\ \hline Working Peak Reverse Voltage & V_{RWM} & V_R & & & & & \\ \hline DC Blocking Voltage & V_R & V_R & & & & & \\ \hline Average Rectified Forward Current & I_{F(AV)} & I_{OO} & & & & \\ \hline (Rated V_R, T_C = 140^{\circ}C) & Per Leg & 200 & & & \\ \hline Peak Repetitive Forward Current, & I_{FRM} & 200 & & & \\ \hline (Rated V_R, Square Wave, 20 kHz, T_C = 140^{\circ}C) & Per Leg & 200 & & & \\ \hline Non-Repetitive Peak Surge Current & I_{FSM} & 1500 & A & \\ \hline (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) & Per Leg & 2.0 & & & \\ \hline Peak Repetitive Reverse Current & I_{RRM} & 2.0 & & & \\ \hline Storage Temperature Range & T_{stg} & -55 to +150 & ^{\circ}C & \\ \hline Operating Junction Temperature & T_J & -55 to +150 & ^{\circ}C & \\ \hline Voltage Rate of Change (Rated V_R) & dv/dt & 10,000 & V/\mus & & \\ \hline \end{tabular}$				
Working Peak Reverse Voltage $V_{RWM}$ DC Blocking Voltage $V_{RWM}$ Average Rectified Forward Current $I_{F(AV)}$ (Rated $V_R$ , $T_C = 140^{\circ}$ C)Per Leg Per Device $100$ 200Peak Repetitive Forward Current, (Rated $V_R$ , Square Wave, 20 kHz, $T_C = 140^{\circ}$ C)IFRMAIFRMA(Rated $V_R$ , Square Wave, 20 kHz, $T_C = 140^{\circ}$ C)Per LegPeak Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)IFSMPeak Repetitive Reverse Current (2.0 $\mu$ s, 1.0 kHz)Per LegPer Leg $Z_{.0}$ Storage Temperature Range $T_{stg}$ -55 to +150°COperating Junction Temperature $T_J$ -55 to +150°C	Rating	Symbol	Value	Unit
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Working Peak Reverse Voltage	V <sub>RWM</sub>	60	0
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	(Rated $V_R$ , $T_C = 140^{\circ}C$ ) Per Leg	I <sub>F(AV)</sub>		Ą
(Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)   Image: Conditions Halfwave, Single Phase, 60 Hz)     Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)   Image: Condition Temperature Particle   Image: Condition Temperature Particle   Image: Condition Temperature Particle   A     Storage Temperature Range   Tstg   -55 to +150   °C     Operating Junction Temperature   TJ   -55 to +150   °C	(Rated V <sub>R</sub> , Square Wave,	IFRM	200	A
(2.0 μs, 1.0 kHz) Per Leg 2.0   Storage Temperature Range T <sub>stg</sub> -55 to +150 °C   Operating Junction Temperature TJ -55 to +150 °C	(Surge Applied at Rated Load Conditions	I <sub>FSM</sub>	1500	A
Operating Junction Temperature     TJ     -55 to +150     °C		I <sub>RRM</sub>	2.0	A
	Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> ) dv/dt 10,000 V/ $\mu$ s	Operating Junction Temperature	TJ	-55 to +150	°C
	Voltage Rate of Change (Rated $V_R$ )	dv/dt	10,000	V/µs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



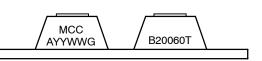
## **ON Semiconductor®**

http://onsemi.com

## SCHOTTKY BARRIER RECTIFIER 200 AMPERES, 60 VOLTS

POWERTAP II CASE 357C PLASTIC

## MARKING DIAGRAM



= Specific Device Code
= Mold Compound Code
= Assembly Location
= Year
= Work Week
= Pb-Free Package

### **ORDERING INFORMATION**

Device	Package	Shipping
MBRP20060CT	POWERTAP II	25 Units/Tray
MBRP20060CTG	POWERTAP II (Pb-Free)	25 Units/Tray

Preferred devices are recommended choices for future use and best overall value.

## THERMAL CHARACTERISTICS (Per Leg)

Instantaneous Reverse Current (Note 1)

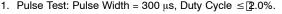
Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R <sub>0JC</sub>	0.6	°C/W
ELECTRICAL CHARACTERISTICS (Per Leg)			
Instantaneous Forward Voltage (Note 1) (i <sub>F</sub> = 200 Amps, T <sub>J</sub> = 25°C)	٧F	0.91	V
(i <sub>F</sub> = 200 Amps, T <sub>J</sub> = 100°C)		0.80	

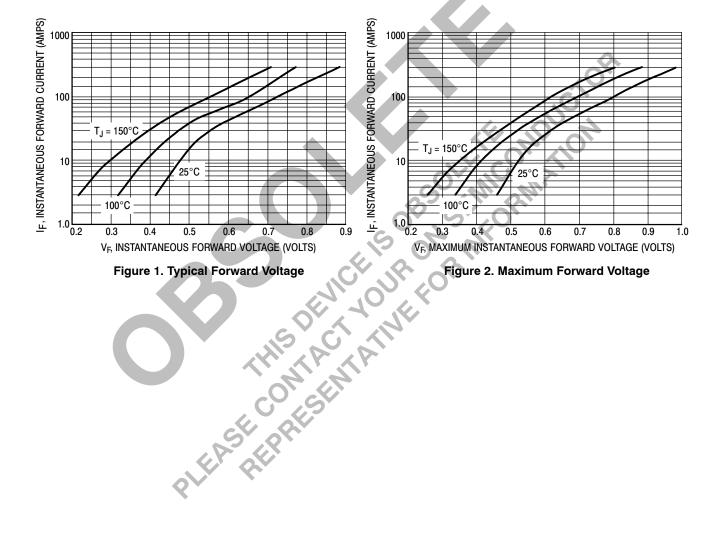
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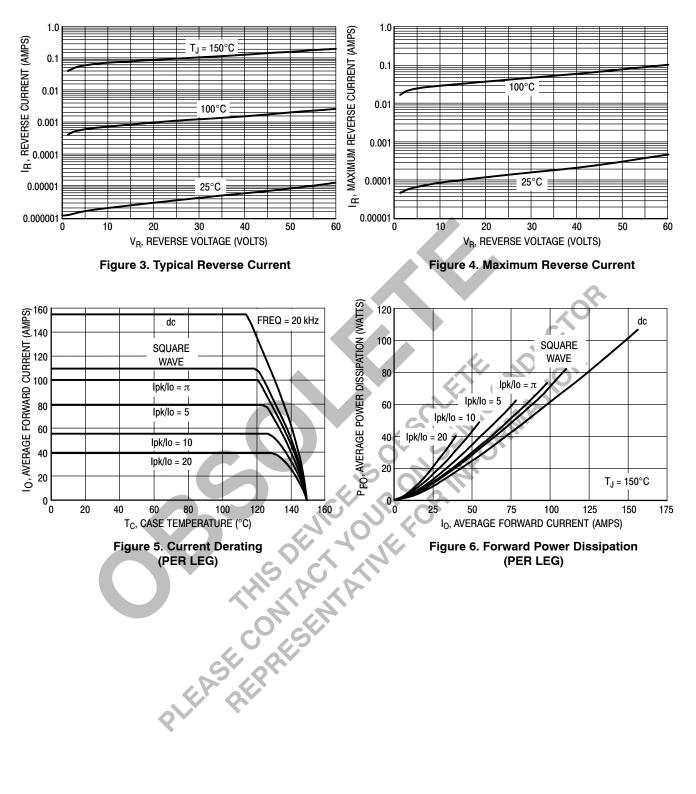
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50 0.5

ļ	(nated do voltage, $T_j = 25 \text{ C}$ )	L (7) 00/
l	(Rated dc Voltage, T <sub>J</sub> = 125°C) (Rated dc Voltage, T <sub>J</sub> = 25°C)	
	(Potod do ) (oltago T. 105°C)	







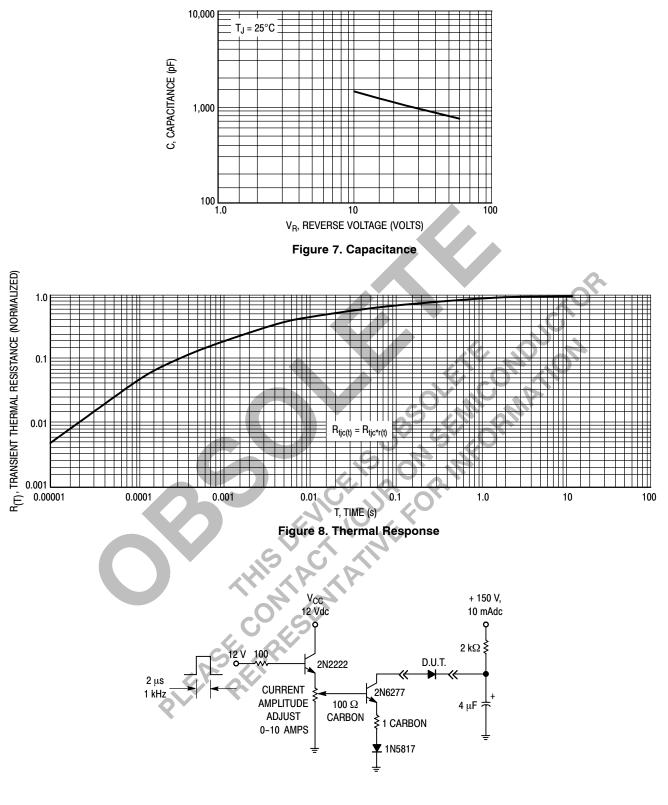
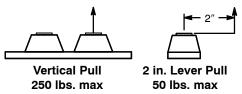


Figure 9. Test Circuit for Repetitive Reverse Current

### MAXIMUM MECHANICAL RATINGS

Terminal Penetration:	0.235 max
Terminal Torque:	25–40 in-lb max
Mounting Torque — Outside Holes:	30–40 in-lb max
Mounting Torque — Center Hole:	8–10 in-lb max
Seating Plane Flatness	1 mil per in. (between mounting holes)

#### POWERTAP MECHANICAL DATA APPLIES OVER OPERATING TEMPERATURE



Note: While the POWERTAP is capable of sustaining these vertical and levered tensions, the intimate contact between POWERTAP and heat sink may be lost. This could lead to thermal runaway. The use of very flexible leads is recommended for the anode connections. Use of thermal grease is highly recommended.

## **MOUNTING PROCEDURE**

The POWERTAP package requires special mounting considerations because of the long longitudinal axis of the copper heat sink. It is important to follow the proper tightening sequence to avoid warping the heat sink, which can reduce thermal contact between the POWERTAP and heat sink.

2-3 TURNS

3 TURNS

10 IN-LB

POWER

HEAT

POWER

HEAT

POWER

HEAT

STEP 1:
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Locate the POWERTAP on the heat sink and start mounting bolts into the threads by hand (2 or 3 turns).

### **STEP 2:**

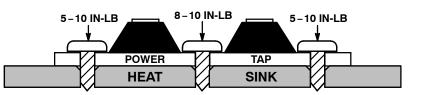
Finger tighten the center bolt. The bolt may catch on the threads of the heat sink so it is important to make sure the face of the bolt or washer is in contact with the surface of the POWERTAP.

## **STEP 3:**

Tighten each of the end bolts between 5 to 10 in-lb.

### **STEP 4:**

Tighten the center bolt between 8 to 10 in-lb.



2-3 TURNS

FINGER-TIGHT

FINGER-TIGHT

-3 TURNS

2-3 TURNS

10 IN-LB

2

TAP

SINK

TAP

SINK

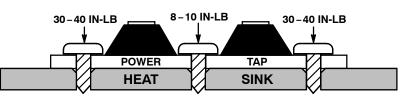
TAP

SINK

5

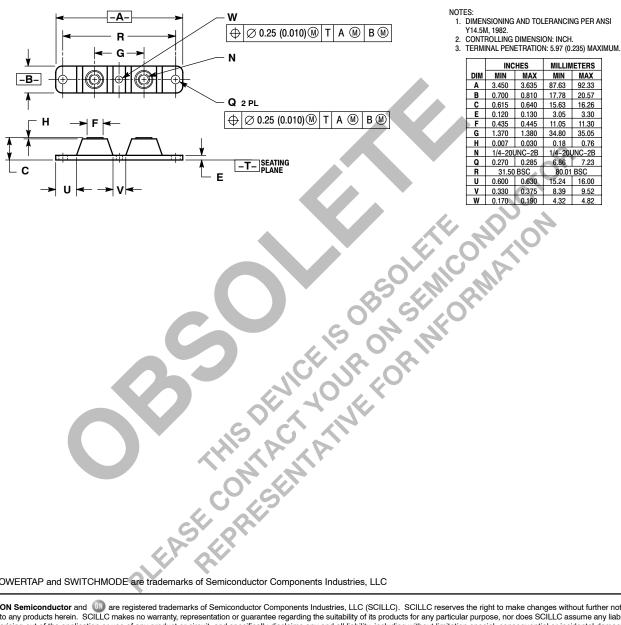
### STEP 5:

Finally, tighten the end bolts between 30 to 40 in-lb.



#### PACKAGE DIMENSIONS

CASE 357C-03 POWERTAP PLASTIC PACKAGE ISSUE E



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